

Hyper 3 mm (T1) LED, Non Diffused Hyper-Bright LED

LS 3336, LO 3336, LY 3336



Besondere Merkmale

- **Gehäusotyp:** nicht eingefärbtes, klares 3 mm (T1) Gehäuse
- **Besonderheit des Bauteils:** Lötspieße mit Aufsetzebene
- **Wellenlänge:** 633 nm (super-rot), 606 nm (orange), 587 nm (gelb)
- **Abstrahlwinkel:** 50°
- **Technologie:** InGaAlP
- **optischer Wirkungsgrad:** 11 lm/W (gelb, orange), 7 lm/W (super-rot)
- **Gruppierungsparameter:** Lichtstärke
- **Lötmethode:** Wellenlöten (TTW)
- **Verpackung:** Schüttgut, gegurtet lieferbar
- **ESD-Festigkeit:** ESD-sicher bis 2 kV nach EOS/ESD-5.1-1993

Anwendungen

- Informationsanzeigen im Innen- und Außenbereich (z. B. im Verkehrsbereich)
- optischer Indikator
- Hinterleuchtung (LCD, Handy, Schalter, Tasten, Displays, Werbebeleuchtung, Allgemeinbeleuchtung)
- Innenbeleuchtung im Automobilbereich (z.B. Instrumentenbeleuchtung, u.ä.)
- Ersatz von Kleinst-Glühlampen
- Markierungsbeleuchtung (z.B. Stufen, Fluchtwege, u.ä.)
- Signal- und Symbolleuchten

Features

- **package:** colorless, clear 3 mm (T1) package
- **feature of the device:** solder leads with stand-off
- **wavelength:** 633 nm (super-red), 606 nm (orange), 587 nm (yellow)
- **viewing angle:** 50°
- **technology:** InGaAlP
- **optical efficiency:** 11 lm/W (yellow, orange), 7 lm/W (super-red)
- **grouping parameter:** luminous intensity
- **soldering methods:** TTW soldering
- **packing:** bulk, available taped on reel
- **ESD-withstand voltage:** up to 2 kV acc. to EOS/ESD-5.1-1993

Applications

- indoor and outdoor displays (e.g. displays for traffic)
- optical indicators
- backlighting (LCD, cellular phones, switches, keys, displays, illuminated advertising, general lighting)
- interior automotive lighting (e.g. dashboard backlighting, etc.)
- substitution of micro incandescent lamps
- marker lights (e.g. steps, exit ways, etc.)
- signal and symbol luminaire

Typ Type	Emissions- farbe Color of Emission	Gehäuse- farbe Color of Package	Lichtstärke Luminous Intensity $I_F = 20 \text{ mA}$ $I_V \text{ (mcd)}$	Lichtstrom Luminous Flux $I_F = 20 \text{ mA}$ $\Phi_V \text{ (mlm)}$	Bestellnummer Ordering Code
LS 3336-QT LS 3336-S LS 3336-T LS 3336-RU LS 3336-TU	super-red	colorless clear	71 ... 450 180 ... 280 280 ... 450 112 ... 710 280 ... 710	390 (typ.) 330 (typ.) 520 (typ.) 620 (typ.) 710 (typ.)	Q62703Q3482 Q62703Q3485 Q62703Q3813 Q62703Q3486 Q65110A0609
LO 3336-RU LO 3336-T LO 3336-U LO 3336-V LO 3336-SV	orange	colorless clear	112 ... 710 280 ... 450 450 ... 710 710 ... 1120 180 ... 1120	600 (typ.) 500 (typ.) 800 (typ.) 1300 (typ.) 940 (typ.)	Q62703Q3144 Q62703Q3170 Q62703Q3307 Q62703Q4688 Q62703Q3177
LY 3336-RU LY 3336-S LY 3336-T LY 3336-U LY 3336-SV	yellow	colorless clear	112 ... 710 180 ... 280 280 ... 450 450 ... 710 180 ... 1120	600 (typ.) 320 (typ.) 500 (typ.) 800 (typ.) 940 (typ.)	Q62703Q3487 Q62703Q3489 Q62703Q3490 Q62703Q3814 Q62703Q3491

Anm.: Die Standardlieferform von Serientypen beinhaltet eine untere bzw. eine obere Familiengruppe oder mindestens zwei Einzelgruppen.

In einer Verpackungseinheit / Gurt ist immer nur eine Helligkeitsgruppe enthalten.

Die technologiebedingte Helligkeits-Streuung der heutigen LED-Herstellprozesse über einen längeren Fertigungszeitraum (Halbleitermaterial - Chipherstellung - Montageprozess) erlaubt keine Zusage einer einzelnen Helligkeitsgruppe. Daher müssen mindestens zwei Helligkeitsgruppen vorgesehen werden!

Note: The standard shipping format for serial types includes a lower or upper family group or at least two individual groups.

No packing unit / tape ever contains more than one luminous intensity group.

Luminosity variations caused by the technology used in current LED manufacturing processes over a protracted manufacturing period (semiconductor material - chip fabrication - assembly process) mean that it is not possible to assign LEDs to a single luminous intensity group. For this reason at least two luminous intensity groups must be provided!.

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Werte Values		Einheit Unit
		LS, LO	LY	
Betriebstemperatur Operating temperature range	T_{op}	- 55 ... + 100		°C
Lagertemperatur Storage temperature range	T_{stg}	- 55 ... + 100		°C
Sperrschichttemperatur Junction temperature	T_j	+ 100		°C
Durchlassstrom Forward current	I_F	30		mA
Stoßstrom Surge current $t \leq 10 \mu s, D = 0.005$	I_{FM}	1	0.2	A
Sperrspannung ¹⁾ Reverse voltage	V_R	12		V
Leistungsaufnahme Power consumption $T_A \leq 25 \text{ °C}$	P_{tot}	80		mW
Wärmewiderstand ²⁾ Thermal resistance Sperrschicht/Umgebung Junction/ambient	$R_{th JA}$	500		K/W
Sperrschicht/Löt看 Junction/solder point Montage auf PC-Board FR 4 (Padgröße $\geq 16 \text{ mm}^2$) mounted on PC board FR 4 (pad size $\geq 16 \text{ mm}^2$) Minimale Beinchenlänge Minimum lead length	$R_{th JS}$	280		K/W

1) für kurzzeitigen Betrieb geeignet / suitable for short term application

2) R_{th} erhöht sich um 13 K/W pro mm Beinchenlänge.
Each additional 1 mm of lead length increases R_{th} by 13 K/W.

Kennwerte ($T_A = 25\text{ °C}$)

Characteristics

Bezeichnung Parameter	Symbol Symbol	Werte Values			Einheit Unit
		LS	LO	LY	
Wellenlänge des emittierten Lichtes (typ.) Wavelength at peak emission $I_F = 20\text{ mA}$	λ_{peak}	645	610	591	nm
Dominantwellenlänge (typ.) Dominant wavelength $I_F = 20\text{ mA}$	λ_{dom}	633	606	587	nm
Spektrale Bandbreite bei 50 % $I_{\text{rel max}}$ (typ.) Spectral bandwidth at 50 % $I_{\text{rel max}}$ $I_F = 20\text{ mA}$	$\Delta\lambda$	16	16	15	nm
Abstrahlwinkel bei 50 % I_V (Vollwinkel) (typ.) Viewing angle at 50 % I_V	2ϕ	50	50	50	Grad deg.
Durchlassspannung ¹⁾ (typ.) Forward voltage ¹⁾ (max.) $I_F = 20\text{ mA}$	V_F V_F	2.0 2.4	2.0 2.4	2.0 2.4	V V
Sperrstrom (typ.) Reverse current (max.) $V_R = 12\text{ V}$	I_R I_R	0.01 10	0.01 10	0.01 10	μA μA
Temperaturkoeffizient von λ_{peak} (typ.) Temperature coefficient of λ_{peak} $I_F = 20\text{ mA}; -10\text{ °C} \leq T \leq 100\text{ °C}$	$TC_{\lambda_{\text{peak}}}$	0.14	0.13	0.13	nm/K
Temperaturkoeffizient von λ_{dom} (typ.) Temperature coefficient of λ_{dom} $I_F = 20\text{ mA}; -10\text{ °C} \leq T \leq 100\text{ °C}$	$TC_{\lambda_{\text{dom}}}$	0.05	0.07	0.10	nm/K
Temperaturkoeffizient von V_F (typ.) Temperature coefficient of V_F $I_F = 20\text{ mA}; -10\text{ °C} \leq T \leq 100\text{ °C}$	TC_V	- 2.0	- 1.7	- 2.5	mV/K
Optischer Wirkungsgrad (typ.) Optical efficiency $I_F = 20\text{ mA}$	η_{opt}	7	11	11	lm/W

¹⁾ Spannungswerte werden mit einer Stromeinprägedauer von 1 ms und einer Genauigkeit von $\pm 0,1\text{ V}$ ermittelt.
Voltages are tested at a current pulse duration of 1 ms and a tolerance of $\pm 0.1\text{ V}$.

Helligkeits-Gruppierungsschema
Luminous Intensity Groups

Lichtgruppe Luminous Intensity Group	Lichtstärke Luminous Intensity I_v (mcd)	Lichtstrom Luminous Flux Φ_v (mlm)
Q	71 ... 112	125 (typ.)
R	112 ... 180	210 (typ.)
S	180 ... 280	320 (typ.)
T	280 ... 450	500 (typ.)
U	450 ... 710	800 (typ.)
V	710 ... 1120	1250 (typ.)

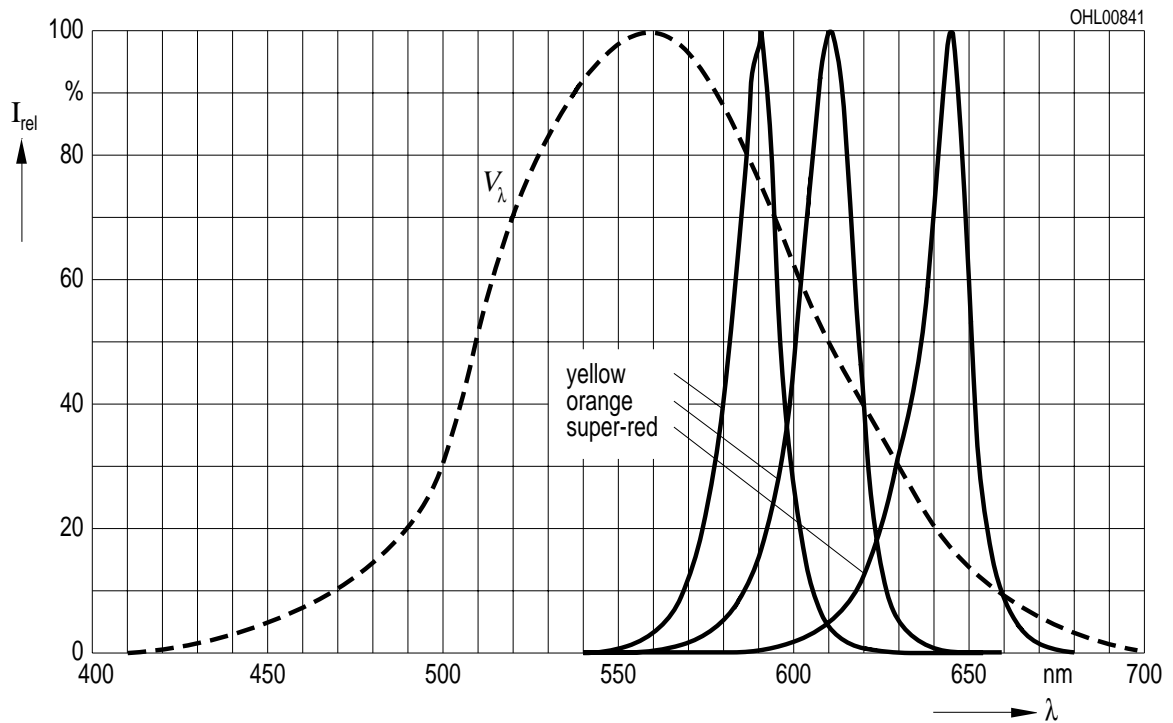
Helligkeitswerte werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 11\%$ ermittelt.
 Luminous intensity is tested at a current pulse duration of 25 ms and a tolerance of $\pm 11\%$.

Relative spektrale Emission $I_{rel} = f(\lambda)$, $T_A = 25\text{ °C}$, $I_F = 20\text{ mA}$

Relative Spectral Emission

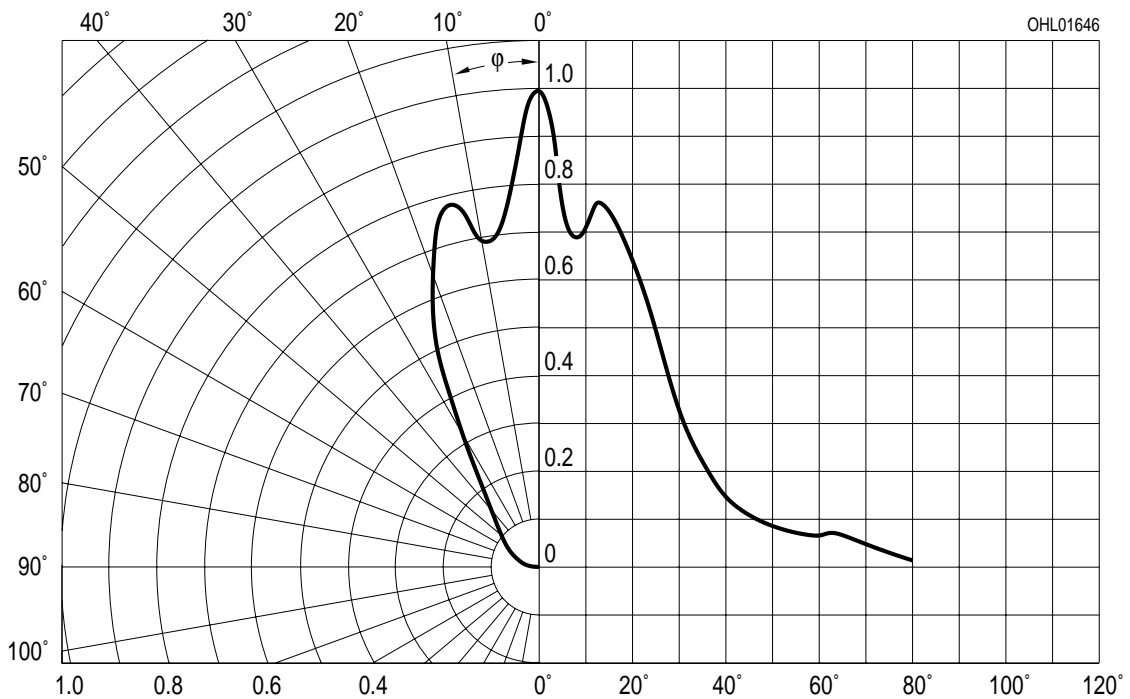
$V(\lambda)$ = spektrale Augenempfindlichkeit

Standard eye response curve



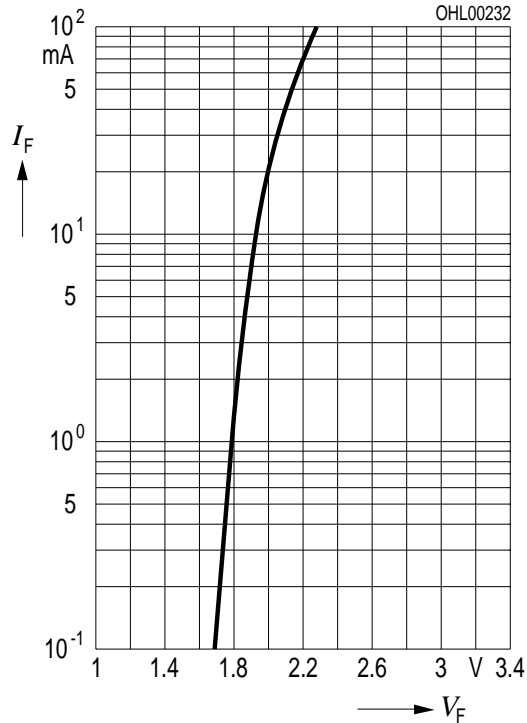
Abstrahlcharakteristik $I_{rel} = f(\varphi)$

Radiation Characteristic



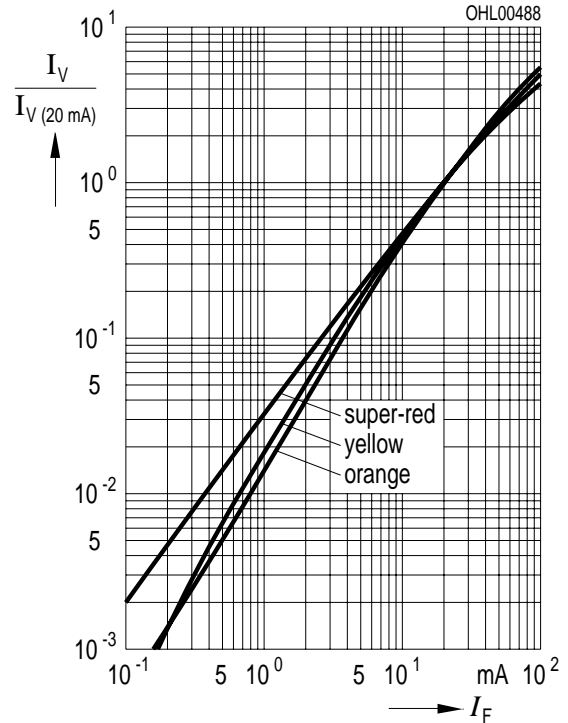
Durchlassstrom $I_F = f(V_F)$
Forward Current

$T_A = 25\text{ °C}$

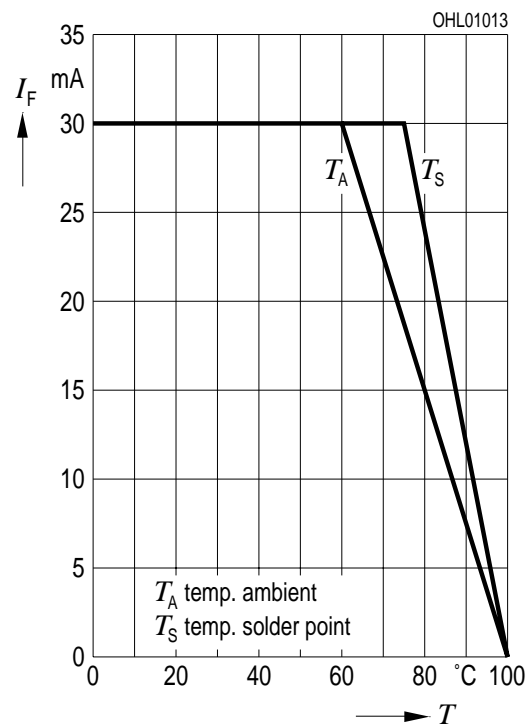


Relative Lichtstärke $I_V/I_{V(20\text{ mA})} = f(I_F)$
Relative Luminous Intensity

$T_A = 25\text{ °C}$

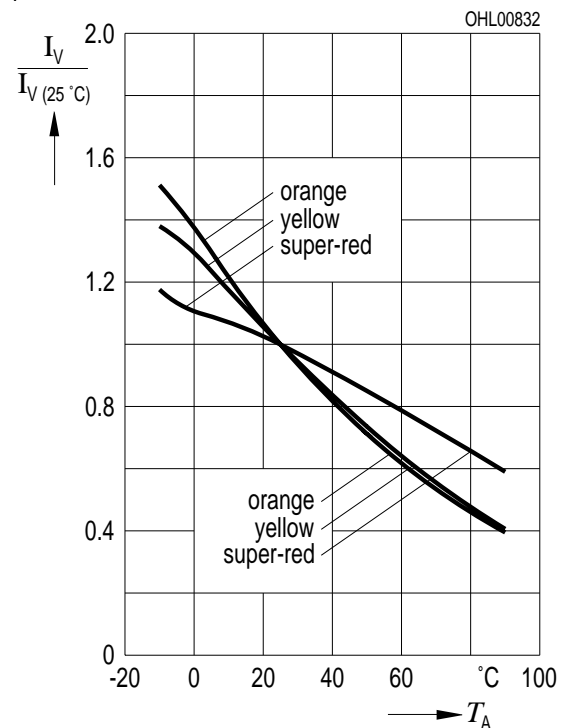


Maximal zulässiger Durchlassstrom $I_F = f(T)$
Max. Permissible Forward Current

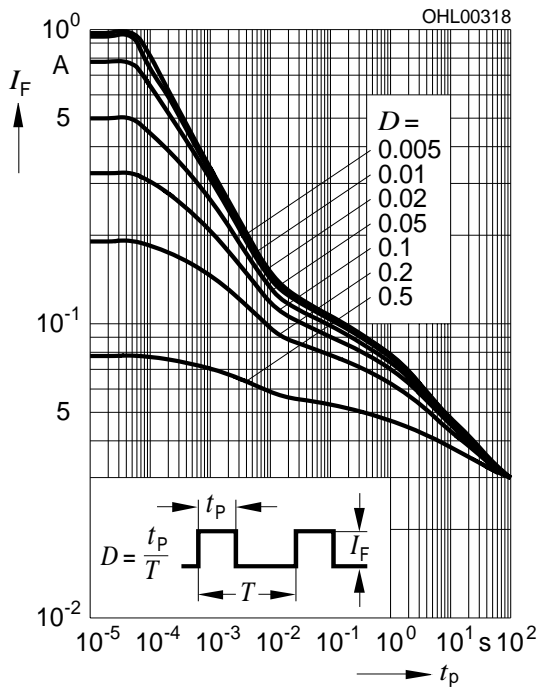


Relative Lichtstärke $I_V/I_{V(25\text{ °C})} = f(T_A)$
Relative Luminous Intensity

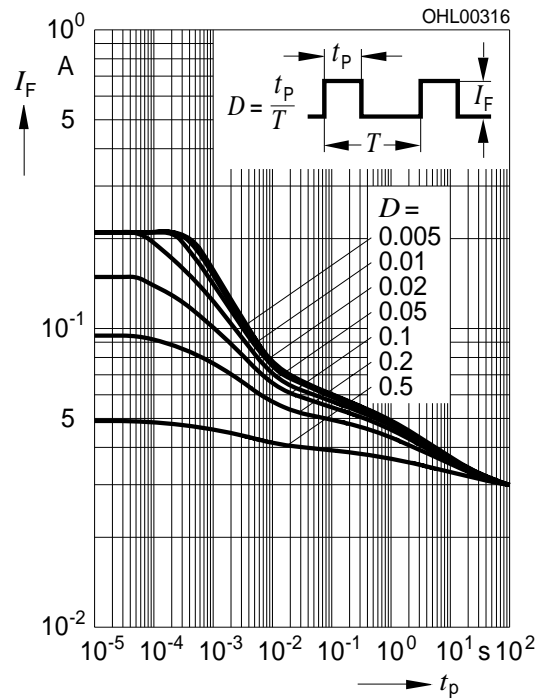
$I_F = 20\text{ mA}$



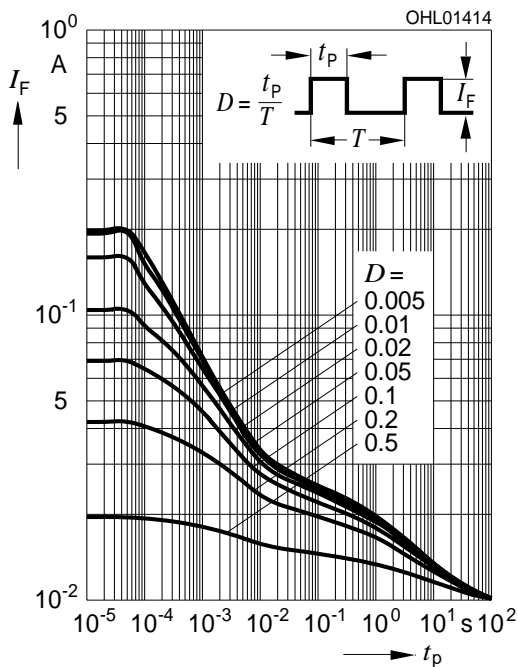
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
 Duty cycle $D =$ parameter, $T_A = 25\text{ °C}$
LS, LO



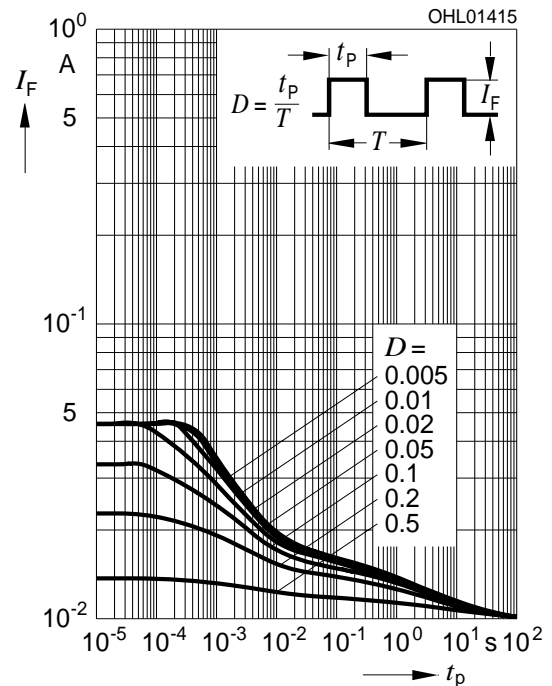
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
 Duty cycle $D =$ parameter, $T_A = 25\text{ °C}$
LY



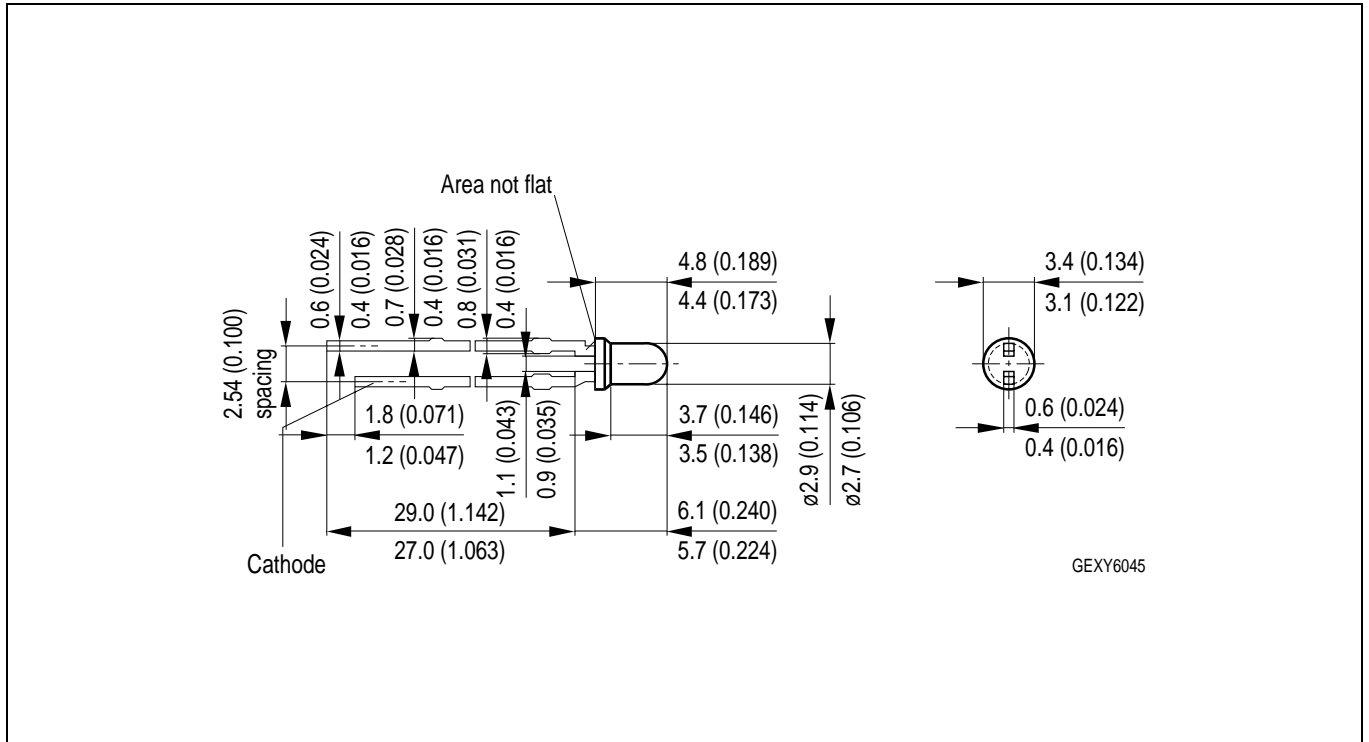
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
 Duty cycle $D =$ parameter, $T_A = 85\text{ °C}$
LS, LO



Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
 Duty cycle $D =$ parameter, $T_A = 85\text{ °C}$
LY



**Maßzeichnung
Package Outlines**

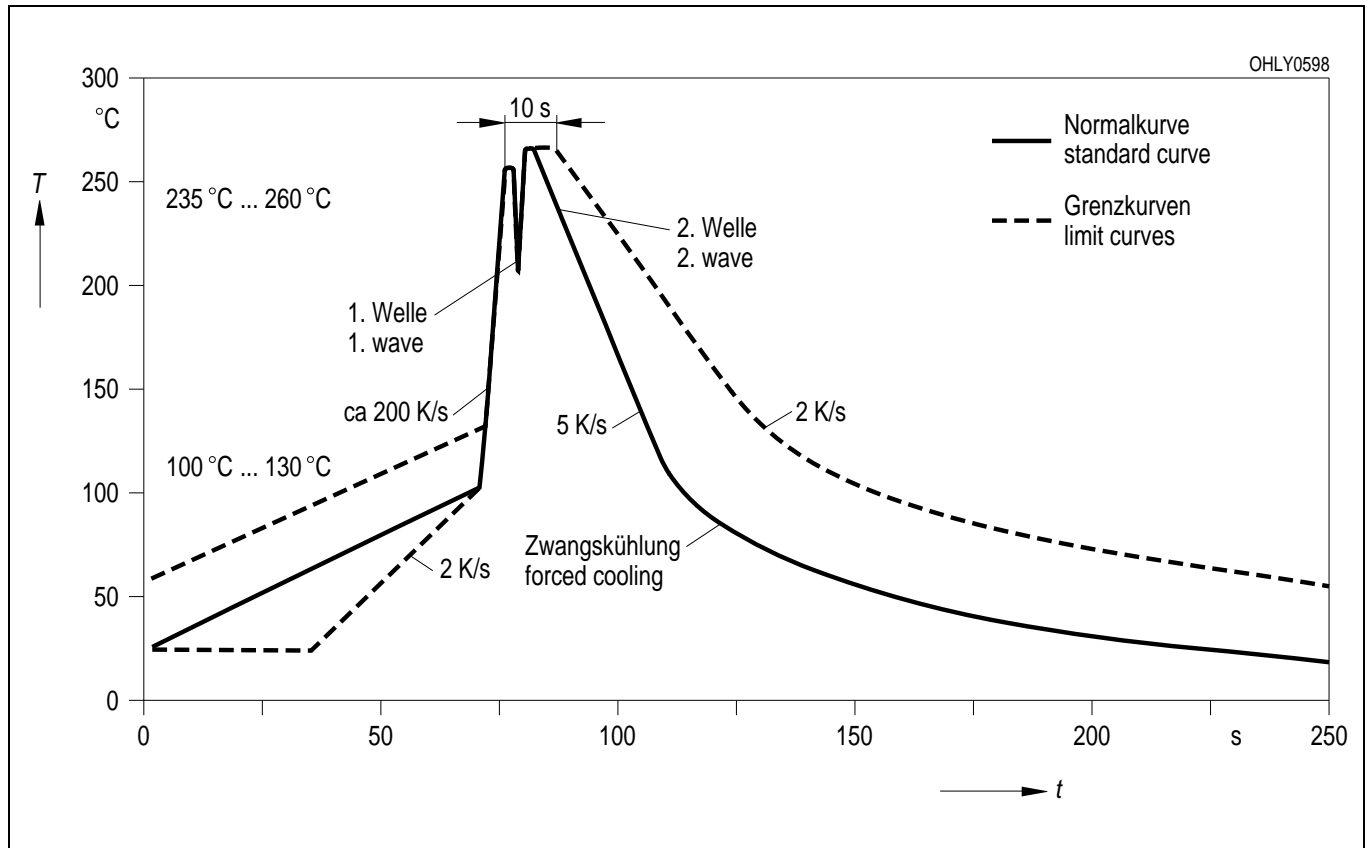


Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

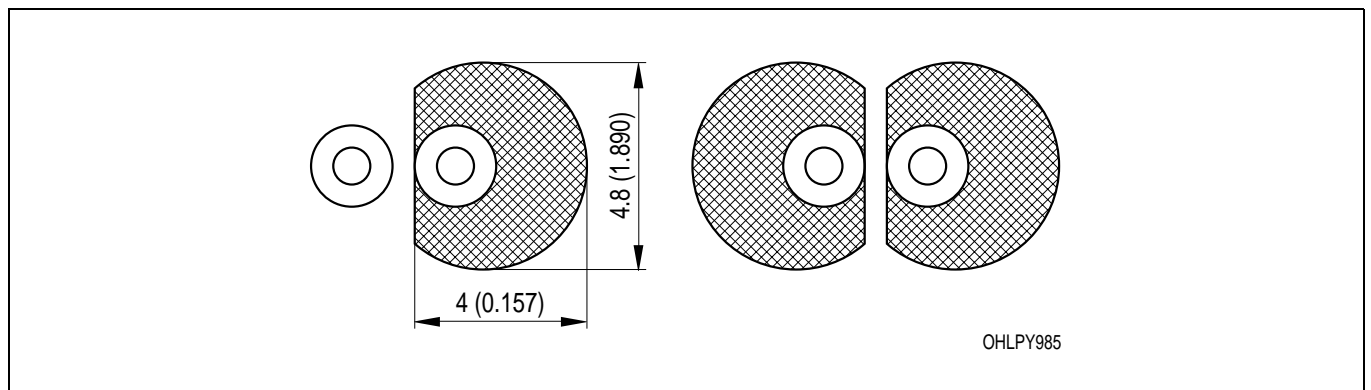
Kathodenkennung: kürzerer Lötspieß
Cathode mark: short solder lead
Gewicht / Approx. weight: 0.15 g

Lötbedingungen
Soldering Conditions

Wellenlöten (TTW) (nach CECC 00802)
TTW Soldering (acc. to CECC 00802)



Empfohlenes Lötpaddesign Wellenlöten (TTW)
Recommended Solder Pad TTW Soldering



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch)

Revision History: 2003-03-11		Date of change
Previous Version: 2003-03-10		
Page	Subjects (major changes since last revision)	
3	thermal resistance (footnote)	
4	value (wavelength amber/yellow)	
10	annotations	2002-07-25
2	not for new designs: amber	2002-07-25
4	value ($TC_{\lambda_{dom}}$ from 0.01 to 0.05 nm/K)	2002-07-25
5	luminous intensity groups	2002-07-30
3, 4	value (reverse voltage from 3 V to 12 V)	2002-09-18
all	removal of "amber"	2002-10-01
7	new diagram for rel. lum. intensity (I_F) (OHL00233 to OHL00488)	2002-10-01
7	new diagram for rel. lum. intensity (T_A) (OHL00238 to OHL00832)	2002-10-01
5	new diagram for rel. spec. emission (OHL00235 to OHL00841)	2002-10-07
2	new type: LO 3336-V	2002-10-02
1	ESD-withstand voltage	2002-12-06
2	new type LS 3336-TU	2003-03-10
all	removal of LS 3336-R	2003-03-11

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² Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health of the user may be endangered.